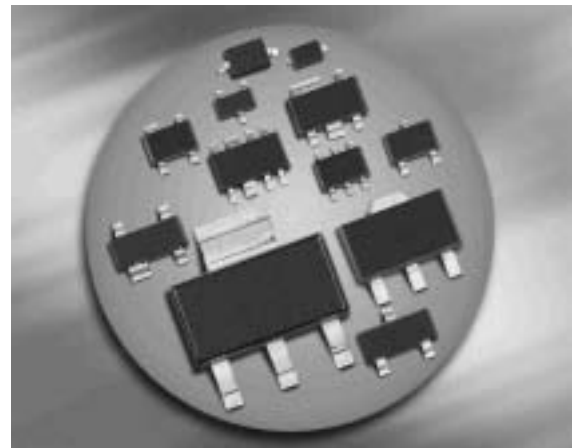
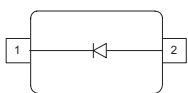


**Silicon Schottky Diodes**

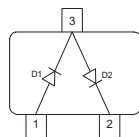
- Low barrier type for DBS mixer applications up to 12 GHz, phase detectors and modulators
- Low noise figure



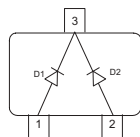
**BAT15-02LRH**  
**BAT15-02V**  
**BAT15-03W**



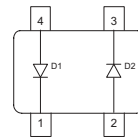
**BAT15-04W**



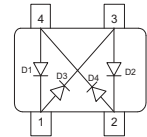
**BAT15-05W**



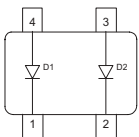
**BAT15-099**  
**BAT15-099LRH**



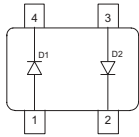
**BAT15-099R**



**BAT15-07LRH**



**BAT-098LRH**



**ESD: Electrostatic discharge sensitive device, observe handling precaution!**

Type	Package	Configuration	$L_S$ (nH)	Marking
BAT15-02LRH*	TSLP-2-7	single, leadless	0.4	NP
BAT15-02V	SC79	single	0.6	n
BAT15-03W	SOD323	single	1.8	P white
BAT15-04W	SOT323	series	1.4	S8s
BAT15-05W	SOT323	common cathode	1.4	S5s
BAT15-07LRH*	TSLP-4-7	parallel pair, leadless	0.4	NP
BAT15-098LRH*	TSLP-4-7	anti-parallel pair, leadless	0.4	B
BAT15-099	SOT143	anti-parallel pair	2	S5s
BAT15-099R	SOT143	crossover ring	2	S6s
BAT15-099LRH*	TSLP-4-7	anti-parallel pair, leadless	0.4	S5

\* preliminary data

**Maximum Ratings at  $T_A = 25^\circ\text{C}$ , unless otherwise specified**

Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_R$	4	V
Forward current	$I_F$	110	mA
Total power dissipation	$P_{\text{tot}}$		mW
BAT15-02LRH, -07LRH, $T_S \leq 76^\circ\text{C}$		100	
BAT15-02V, $T_S \leq 72^\circ\text{C}$		100	
BAT15-03W, $T_S \leq 70^\circ\text{C}$		100	
BAT15-04W, $T_S \leq 68^\circ\text{C}$		100	
BAT15-05W, $T_S \leq 65^\circ\text{C}$		100	
BAT15-099, $T_S \leq 48^\circ\text{C}$		100	
BAT15-099R, $T_S \leq 67^\circ\text{C}$		100	
BAT15-098LRH, -099LRH $T_S \leq 76^\circ\text{C}$		100	
Junction temperature	$T_j$	150	°C
Operating temperature range	$T_{\text{op}}$	-55 ... 150	
Storage temperature	$T_{\text{stg}}$	-55 ... 150	

**Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	$R_{\text{thJS}}$		K/W
BAT15-02LRH, BAT15-02V, BAT15-07LRH		$\leq 780$	
BAT15-03W		$\leq 795$	
BAT15-04W		$\leq 820$	
BAT15-05W		$\leq 850$	
BAT15-099		$\leq 1020$	
BAT15-099R		$\leq 830$	
BAT15-098LRH, BAT15-099LRH		$\leq 780$	

<sup>1</sup>For calculation of  $R_{\text{thJA}}$  please refer to Application Note Thermal Resistance

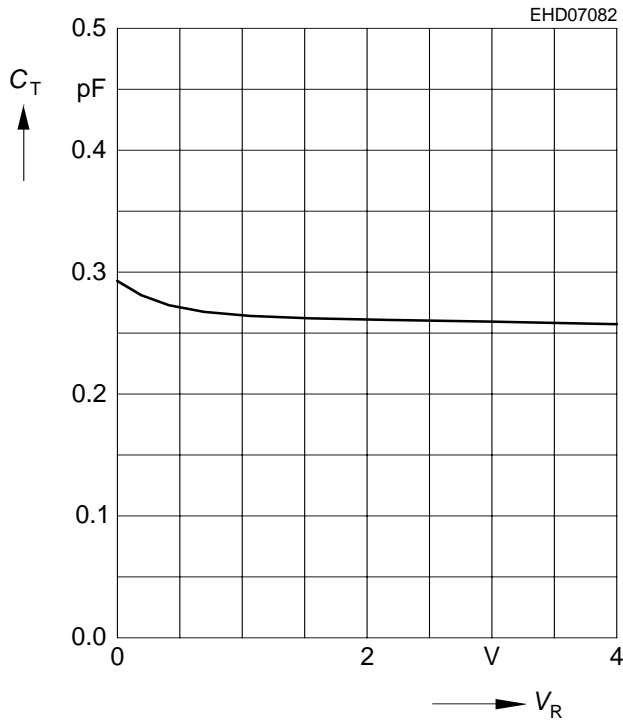
**Electrical Characteristics at  $T_A = 25^\circ\text{C}$ , unless otherwise specified**

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
<b>DC Characteristics</b>					
Breakdown voltage $I_{(BR)} = 100 \mu\text{A}$	$V_{(BR)}$	4	-	-	V
Forward voltage $I_F = 1 \text{ mA}$ $I_F = 10 \text{ mA}$	$V_F$	0.16 0.25	0.23 0.32	0.32 0.41	
Forward voltage matching <sup>1)</sup> $I_F = 10 \text{ mA}$	$\Delta V_F$	-	-	20	mV
<b>AC Characteristics</b>					
Diode capacitance $V_R = 0 \text{ V}, f = 1 \text{ MHz}$	$C_T$	-	-	0.35	pF
Differential forward resistance $I_F = 10 \text{ mA} / 50 \text{ mA}$	$R_F$	-	5.5	-	$\Omega$

<sup>1)</sup> $\Delta V_F$  is the difference between lowest and highest  $V_F$  in a multiple diode component.

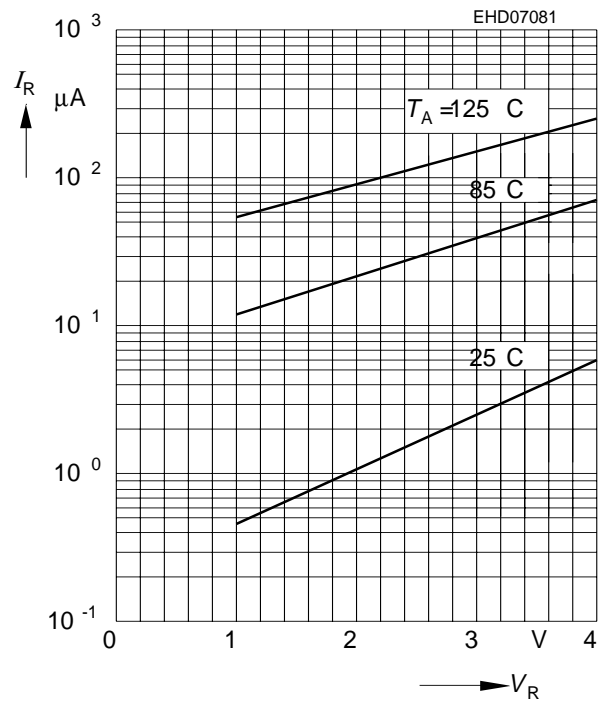
**Diode capacitance  $C_T = f(V_R)$**

$f = 1\text{MHz}$



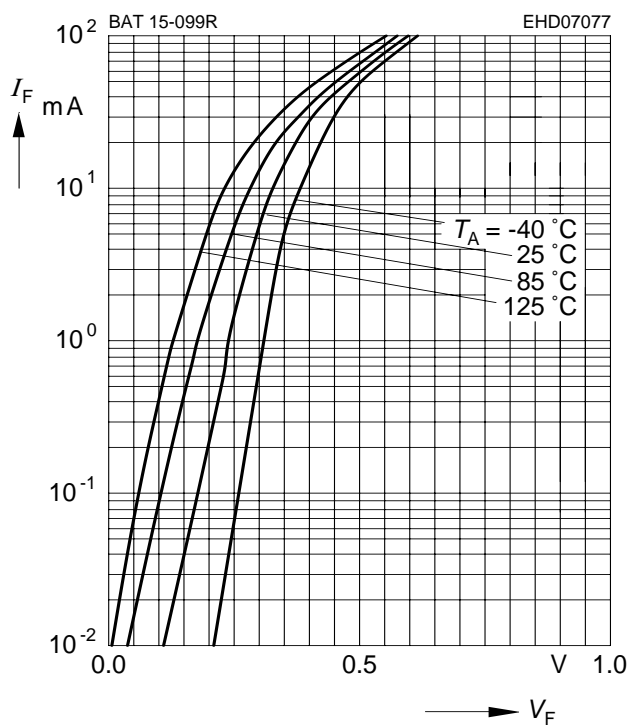
**Reverse current  $I_R = f(V_R)$**

$T_A = \text{Parameter}$



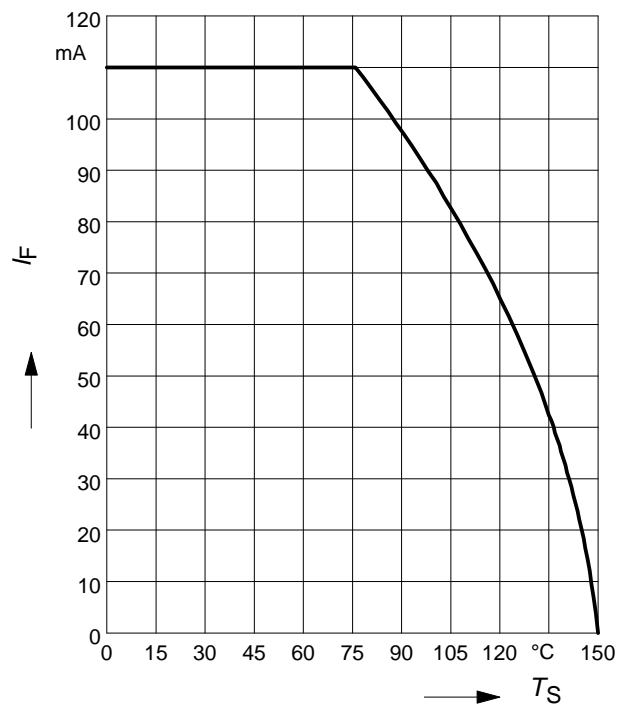
**Forward current  $I_F = f(V_F)$**

$T_A = \text{Parameter}$



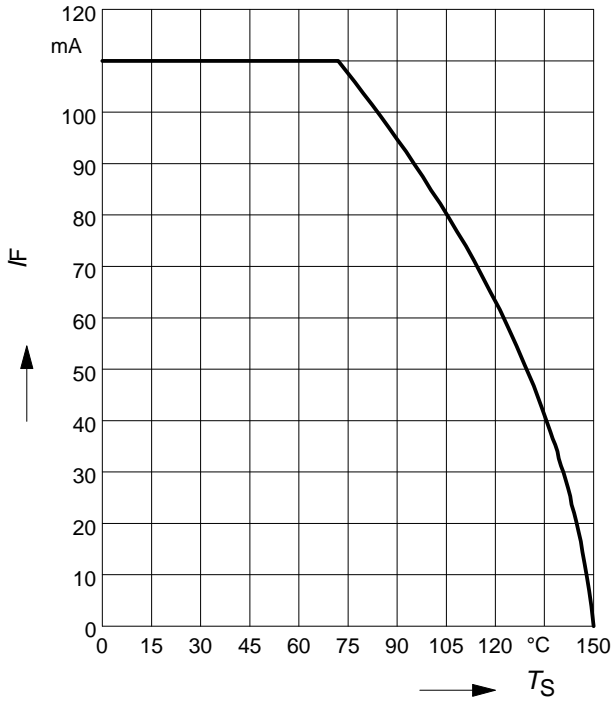
**Forward current  $I_F = f(T_S)$**

BAT15-02LRH, BAT15-07LRH  
BAT15-098LRH, BAT15-099LRH



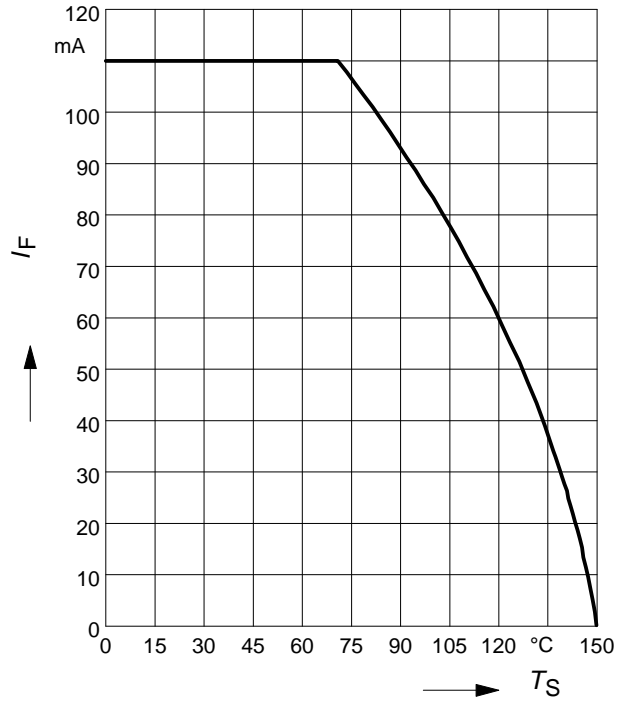
Forward current  $I_F = f(T_S)$

BAT15-02V



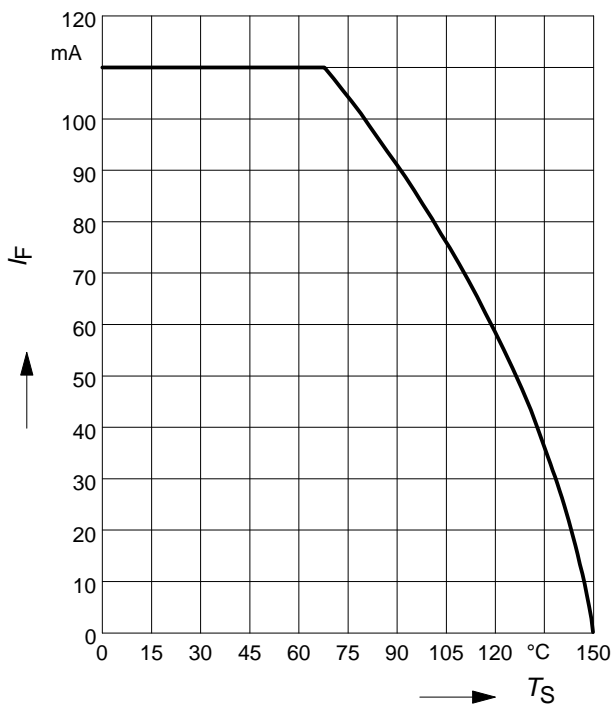
Forward current  $I_F = f(T_S)$

BAT15-03W



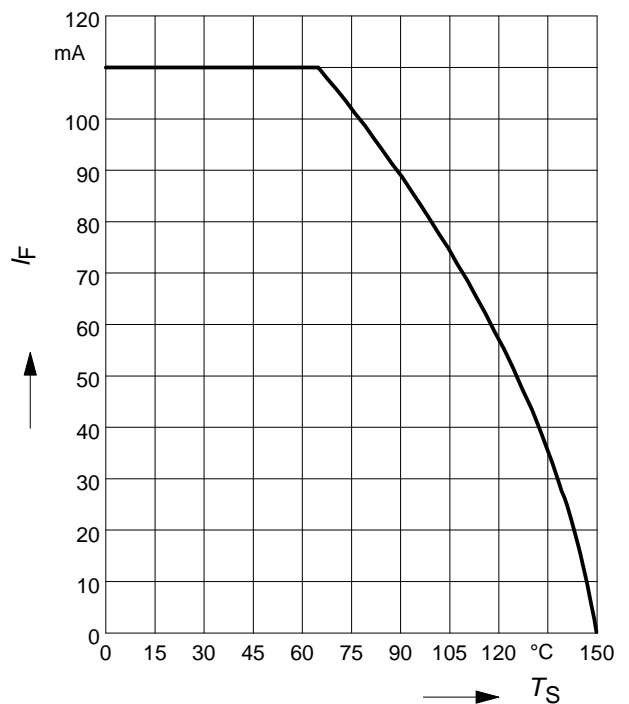
Forward current  $I_F = f(T_S)$

BAT15-04W



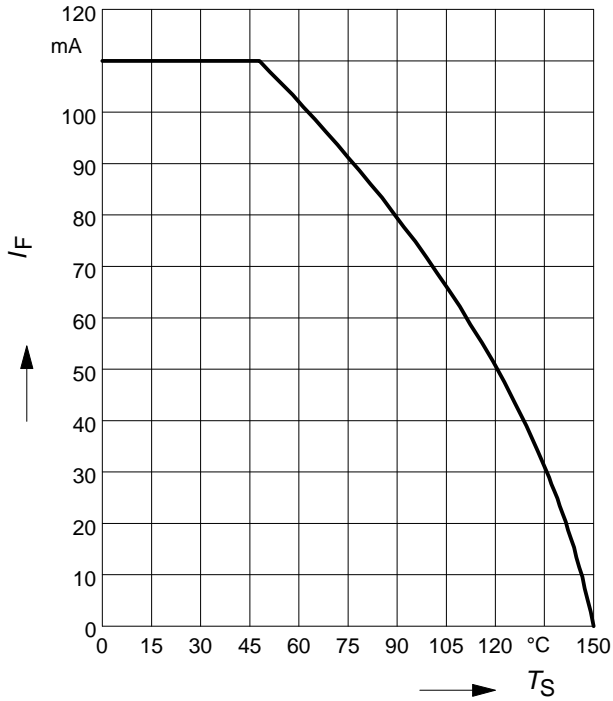
Forward current  $I_F = f(T_S)$

BAT15-05W



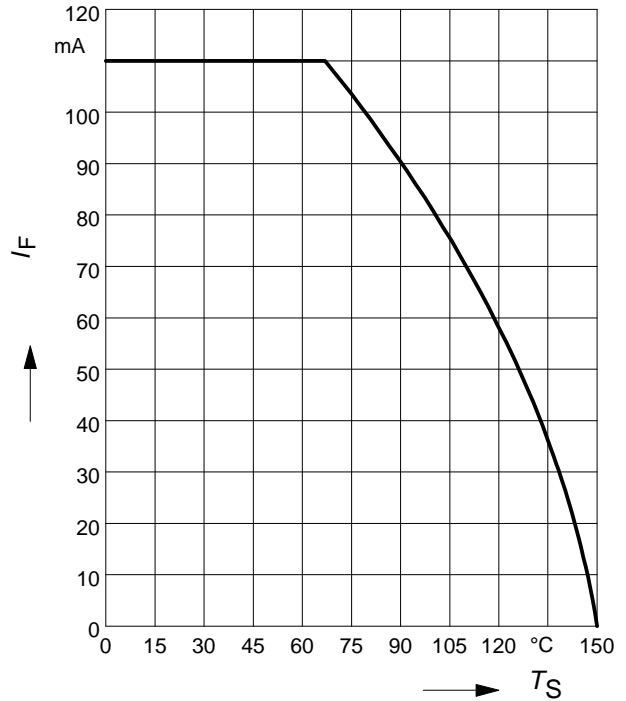
**Forward current  $I_F = f(T_S)$**

BAT15-099



**Forward current  $I_F = f(T_S)$**

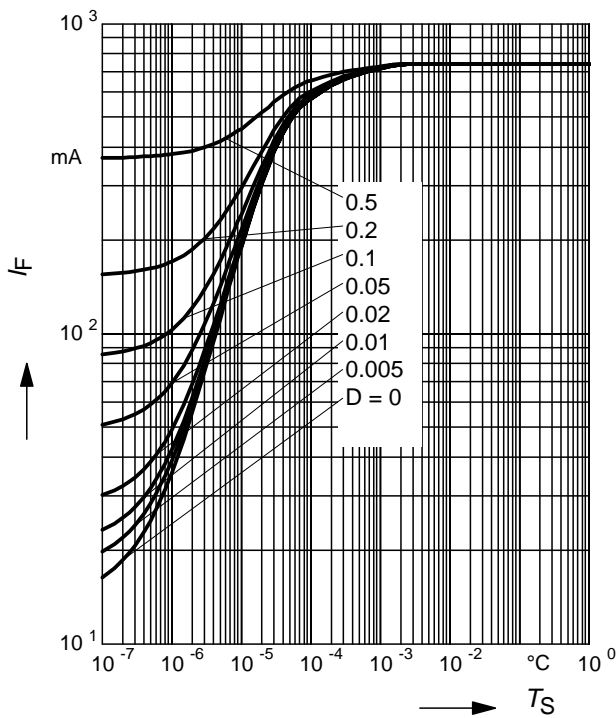
BAT15-099R



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

BAT15-02LRH, BAT15-07LRH

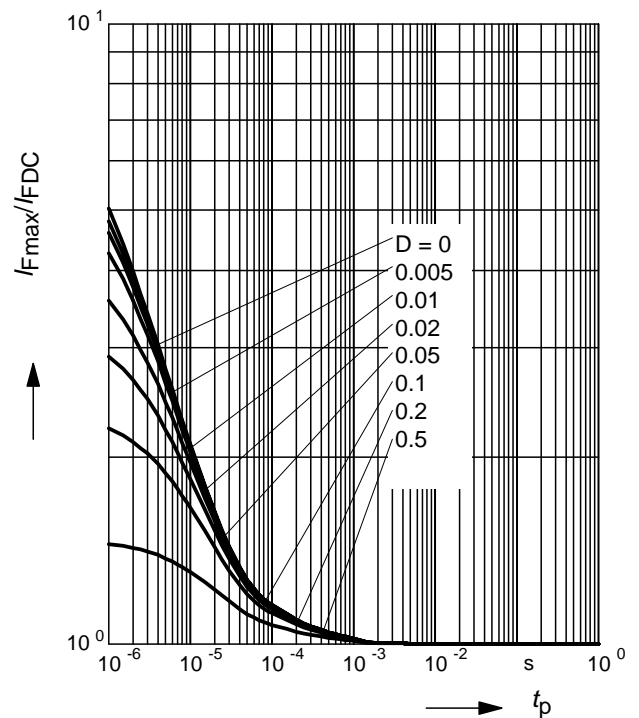
BAT15-098LRH, BAT15-099LRH



**Permissible Pulse Load**

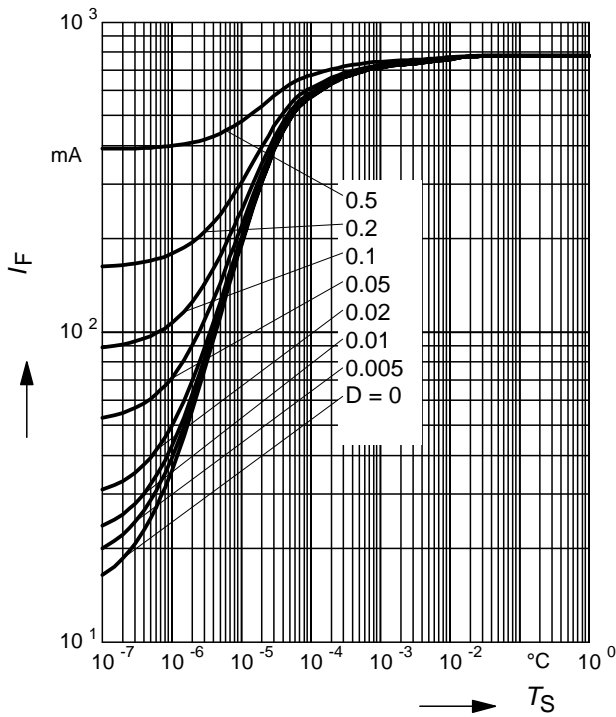
$I_{Fmax}/I_{FDC} = f(t_p)$  BAT15-02LRH, -07LRH

BAT15-098LRH, BAT15-099LRH



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

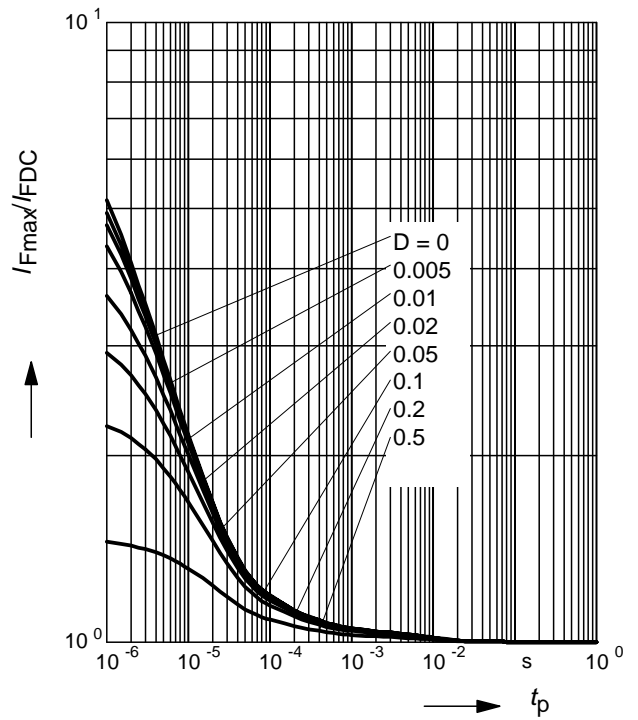
BAT15-02V



**Permissible Pulse Load**

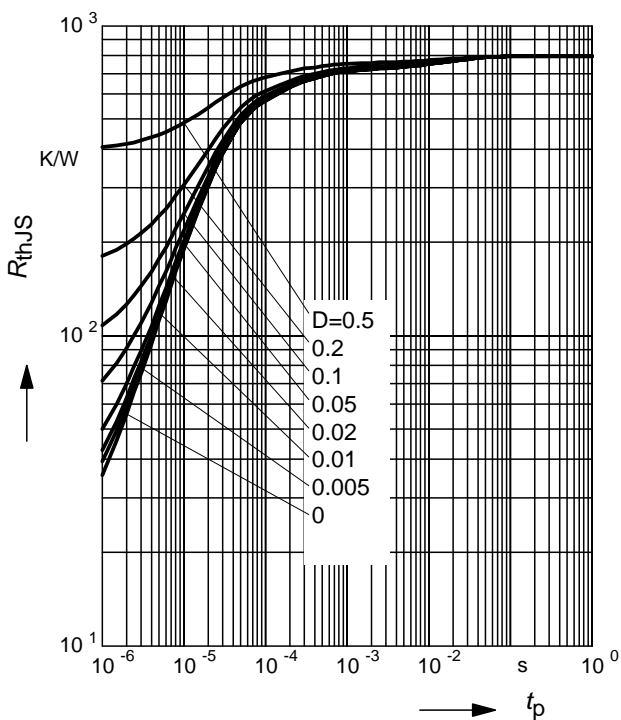
$I_{Fmax} / I_{FDC} = f(t_p)$

BAT15-02V



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

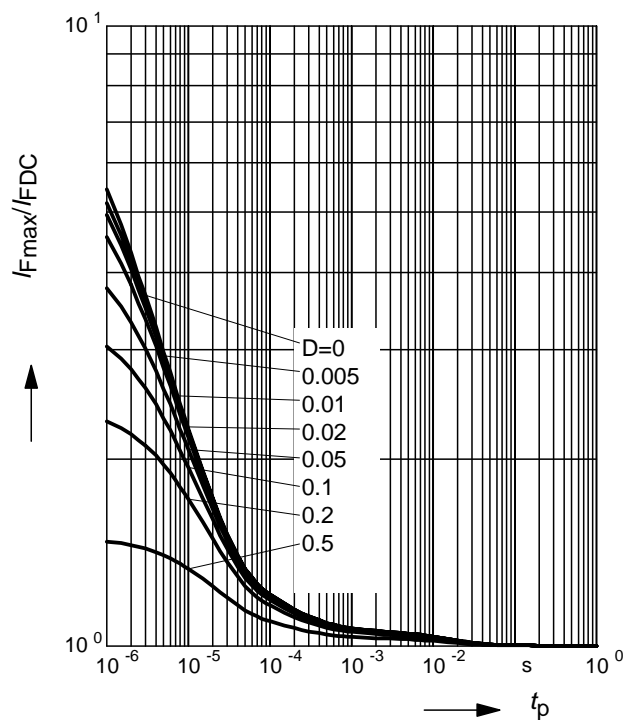
BAT15-03W



**Permissible Pulse Load**

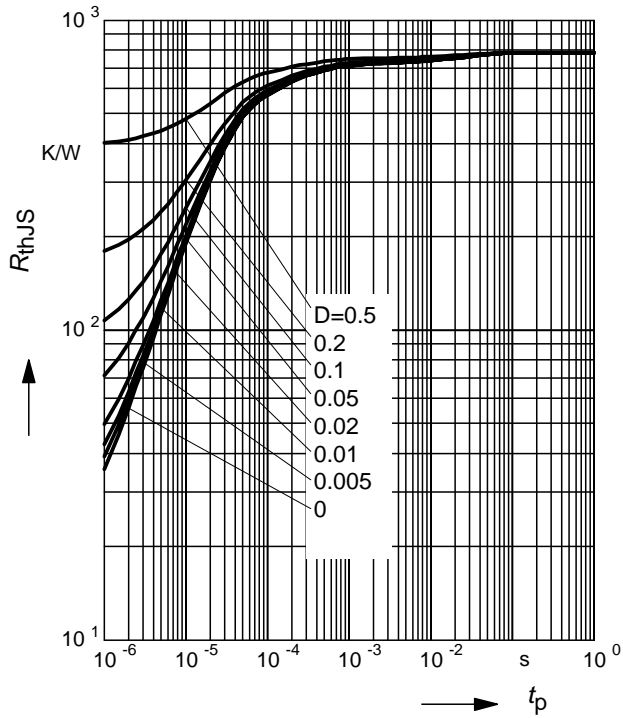
$I_{Fmax} / I_{FDC} = f(t_p)$

BAT15-03W



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

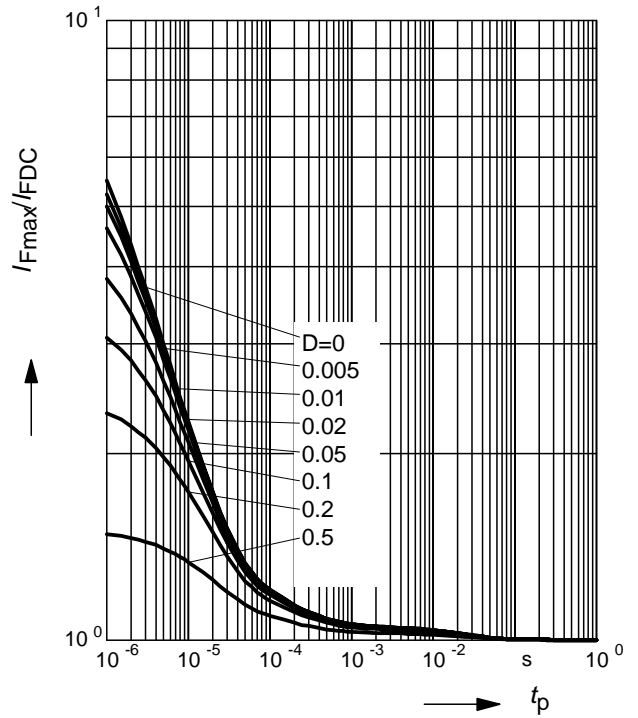
BAT15-04W



**Permissible Pulse Load**

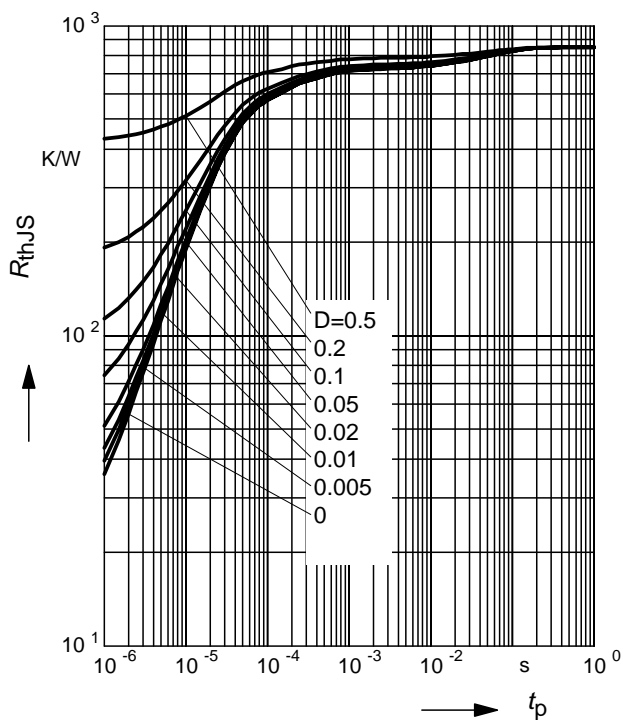
$I_{Fmax} / I_{FDC} = f(t_p)$

BAT15-04W



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

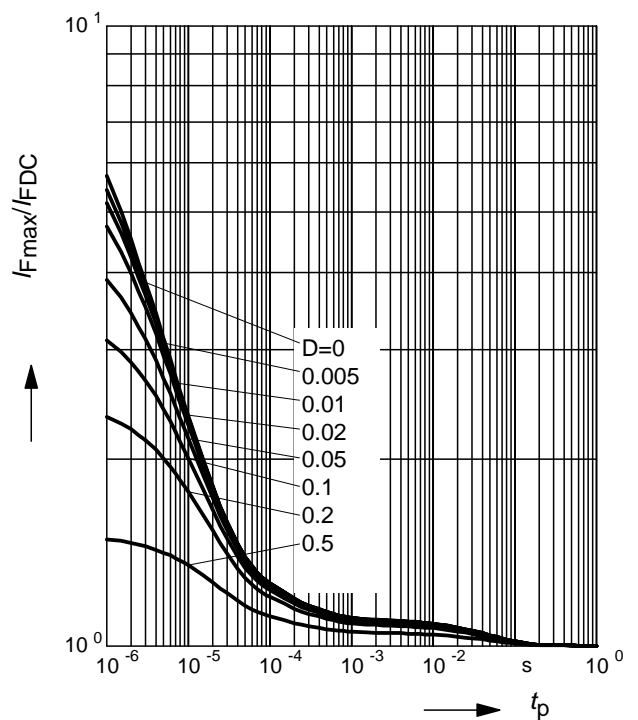
BAT15-05W



**Permissible Pulse Load**

$I_{Fmax} / I_{FDC} = f(t_p)$

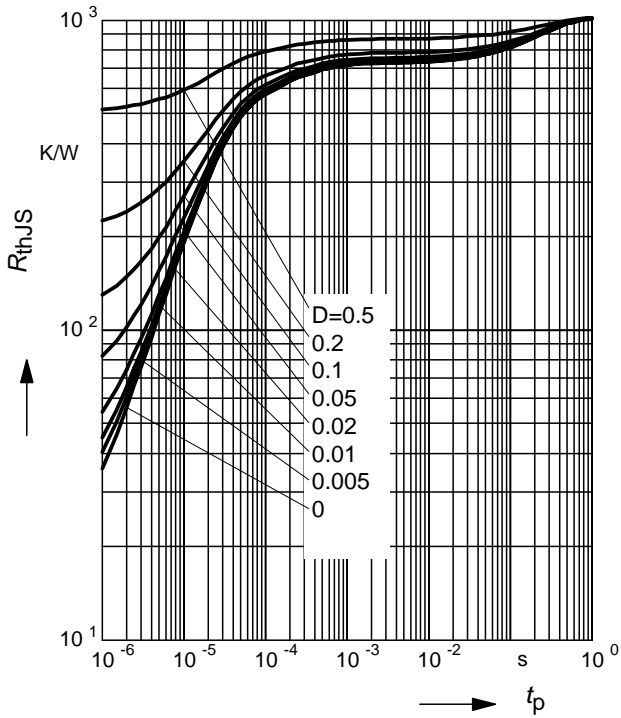
BAT15-05W





**Permissible Puls Load  $R_{thJS} = f(t_p)$**

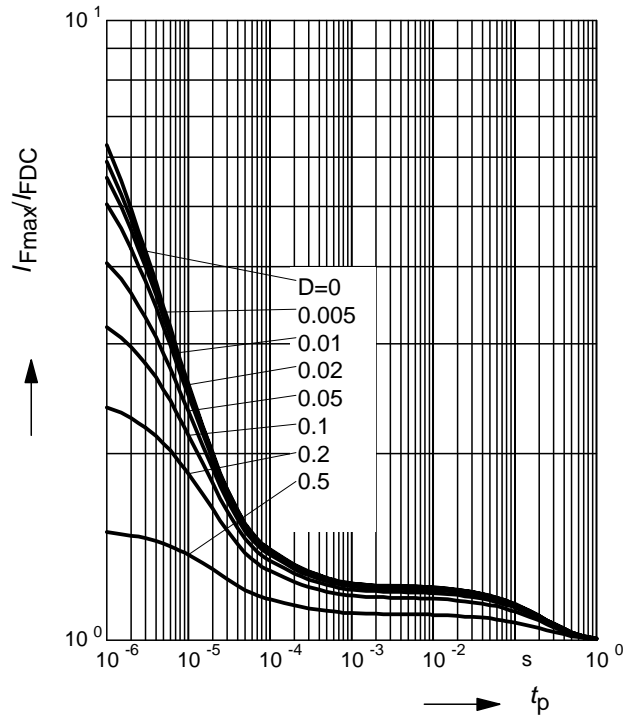
BAT15-099



**Permissible Pulse Load**

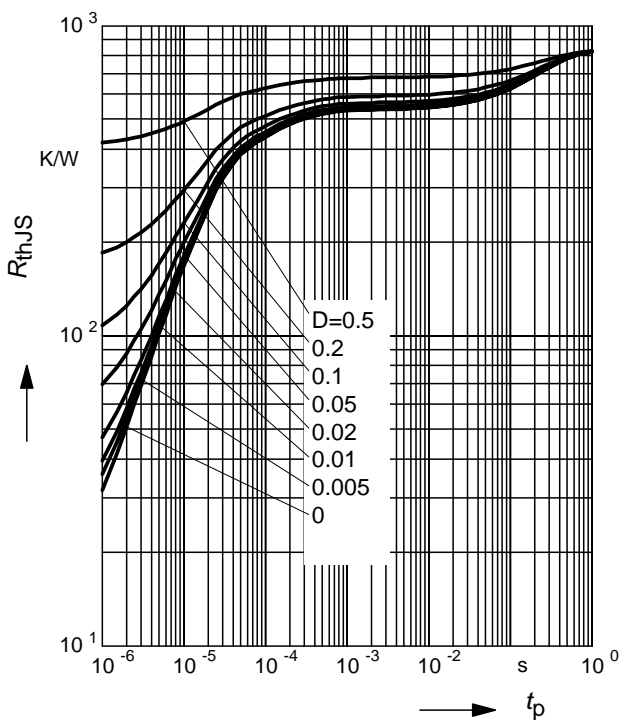
$I_{Fmax} / I_{FDC} = f(t_p)$

BAT15-099



**Permissible Puls Load  $R_{thJS} = f(t_p)$**

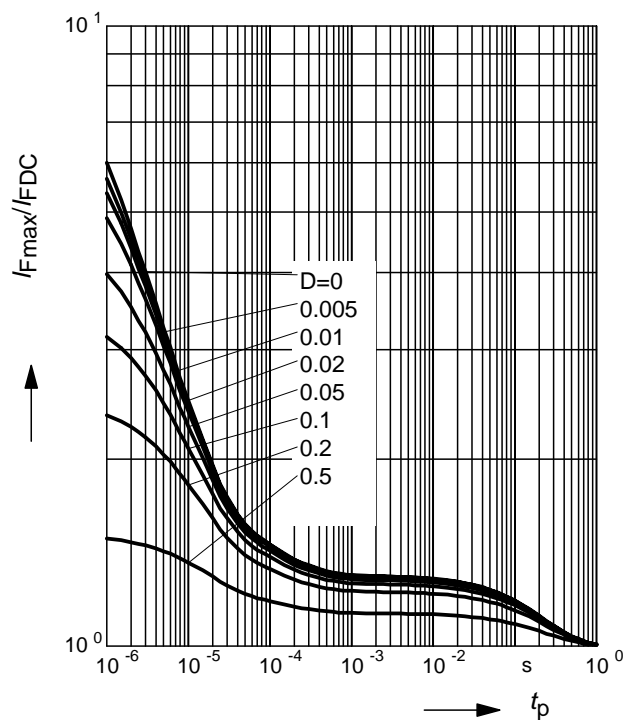
BAT15-099R



**Permissible Pulse Load**

$I_{Fmax} / I_{FDC} = f(t_p)$

BAT15-099R

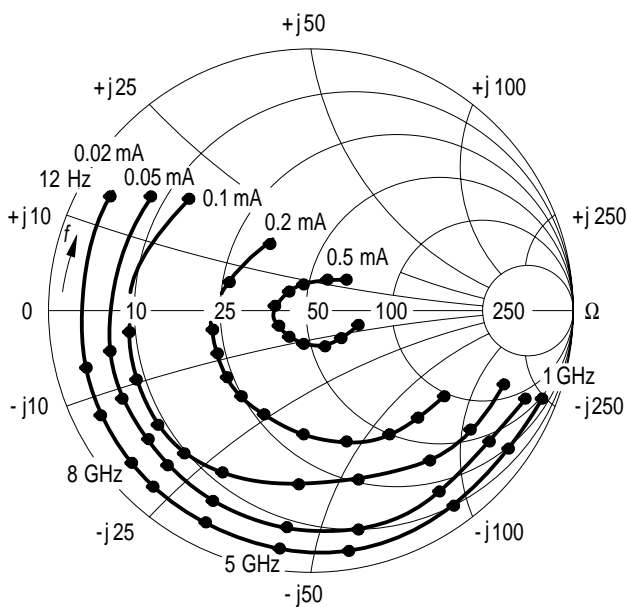


**S<sub>11</sub>-Parameters for BAT15-099**

Typical impedance characteristics (with external bias *I* and *Z*<sub>0</sub> = 50Ω)

<i>f</i>	<i>I</i> = 0.02 mA		<i>I</i> = 0.05 mA		<i>I</i> = 0.1 mA		<i>I</i> = 0.2 mA		<i>I</i> = 0.5 mA	
GHz	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
1	0.94	-16.4	0.84	-16.6	0.77	-16.4	0.59	-17.2	0.19	-16.7
2	0.93	-33.8	0.88	-33.8	0.77	-34.5	0.58	-35.2	0.15	-36.1
3	0.92	-53.8	0.86	-54.5	0.75	-54.1	0.58	-56.1	0.13	-64.8
4	0.91	-74.3	0.84	-75.3	0.72	-76.4	0.51	-78.4	0.11	-104.8
5	0.91	-96.6	0.84	-97.6	0.72	-99.1	0.53	-102.3	0.15	-135.7
6	0.91	-115.4	0.84	-116.7	0.73	-118.7	0.53	-122.9	0.18	-160.9
7	0.91	-131	0.84	-132.3	0.73	-134.1	0.54	-138.1	0.2	-168.8
8	0.91	-143	0.84	-144.5	0.73	-146.8	0.55	-150.5	0.81	179.4
9	0.91	-155.6	0.83	-150.2	0.71	-159.7	0.53	-163.9	0.18	179.4
10	0.9	-167.3	0.83	-169.7	0.71	-178.8	0.51	-175.8	0.14	151.2
11	0.89	175.5	0.8	172.6	0.7	170	0.45	164.9	0.09	105.5
12	0.88	175.5	0.76	146.5	0.62	142.8	0.39	134.2	0.14	43.6

**S<sub>11</sub> = (*f*, *I*) BAT15-099**



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